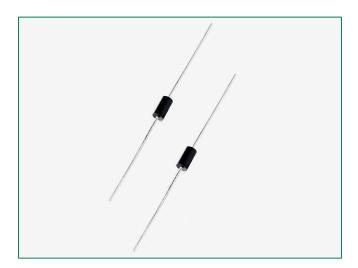


1N5908





Maximum Ratings and Thermal Characteristics

Rating	Symbol	Value	Unit
Peak Power Dissipation (Note 1) @ T _L " 25°C	P _{PK}	1500	W
Steady State Power Dissipation @ T_L "75°C, Lead Length = 3/8 \leq Derated above T_L = 75°C	P _{PK}	5.0 50	W mW/°C
Thermal Resistance, Junction-to-Lead	R _{8JL}	20	°C/W
Forward Surge Current (Note 2) @TA = 25°C	I _{FSM}	200	А
Operating and Storage Temperature Range	T _J , T _{stg}	-65 to +175	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. Nonrepetitive current pulse per Figure 4 and derated above $TA = 25^{\circ}C$ per Figure 2.
- 2. 1/2 sine wave (or equivalent square wave), PW = 8.3 ms, duty cycle = 4 pulses per minute maximum.
- *Bidirectional device will not be available in this device

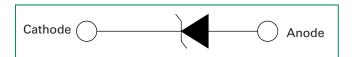
Description

These devices are designed to protect voltage sensitive components from high voltage, high-energy transients. They have excellent clamping capability, high surge capability, low zener impedance and fast response time. These devices are the Littelfuse exclusive, cost effective, highly reliable axial leaded package and are ideally suited for use in communication systems, numerical controls, process controls, medical equipment, business machines, power supplies and many other industrial/consumer applications, to protect CMOS, MOS and Bipolar integrated circuits.

Features

- Working Peak Reverse Voltage Range 5.0 V
- Peak Power 1500 Watts @ 1 ms
- Maximum Clamp Voltage @ Peak Pulse Current
- Low Leakage < 5 μA Above 10 V
- Response Time is Typically < 1 ns
- These are Pb-Free Devices*

Functional Diagram



Additional Information

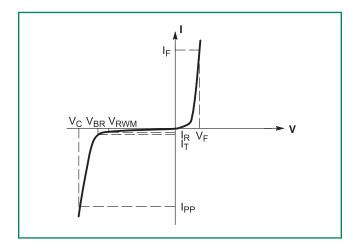








I-V Curve Characteristics $\{T_A = 25^{\circ}\text{C unless otherwise noted}, V_F = 3.5 \text{ V Max.} @ I_F \text{ (Note 3)} = 100 \text{ A}\}$



Symbol	Parameter	
I _{PP}	Maximum Reverse Peak Pulse Current	
V _C	Clamping Voltage @ I _{pp}	
V _{RWM}	Working Peak Reverse Voltage	
I _R	Maximum Reverse Leakage Current @ V _{RWM}	
V _{BR}	Breakdown Voltage @ I _T	
I _T	Test Current	
I _F	Forward Current	
V _F	Forward Voltage @ I _F	

Ratings and Characteristic Curves

Figure 1. Pulse Rating Curve

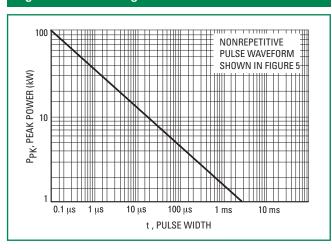


Figure 2. Pulse Derating Curve

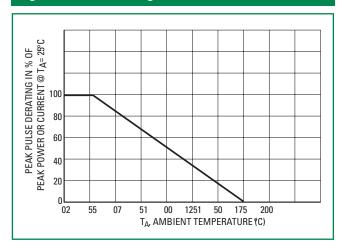


Figure 3. Steady State Power Derating

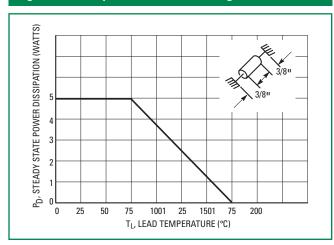


Figure 4. Pulse Waveform

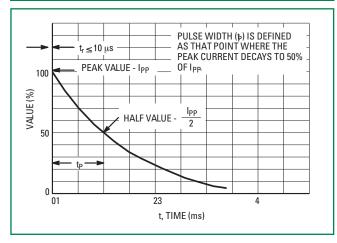
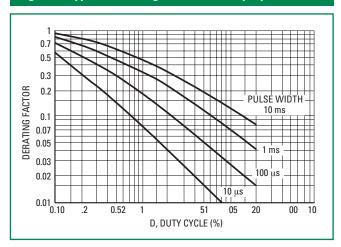
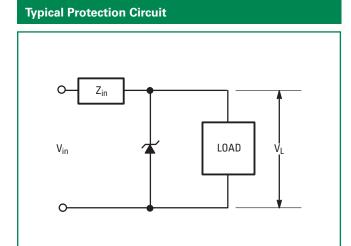




Figure 5. Typical Derating Factor for Duty Cycle







TVS Diodes

Axial > 1500W > 1N5908

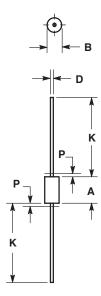
Electrical Characteristics (TA = 25 ° C unless otherwise noted, VF = 3.5 V Max. @ IF (Note 3) = 53 A)

V _{RWM}		Breakdown Voltage			V _c (Volts) (Note 7)				
Device (Notes 4)	(Note 5)	I @V R RWM	V _{BR} (V) (Note 6)		@I _T	@ _{DD} =	@ L	@ L 20 A	
(Volts)	(μΑ)	Min	Nom	Max	(mA)	@ I _{pp} = 120 A	@ 1 _{PP} = 30 A		
1N5908	5.0	300	6.0	-	-	1.0	8.5	8.0	7.6

- 3. Square waveform, PW = 8.3 ms, Non-repetitive duty cycle.
- 4. 1N5908 is JEDEC registered as a unidirectional device only (no bidirectional option)
- 5. A transient suppressor is normally selected according to the maximum working peak reverse voltage (V_{RMM}), which should be equal to or greater than the dc or continuous peak operating voltage level.
- 6. VBR measured at pulse test current I_T at an ambient temperature of 25°C and minimum voltages in V_{RB} are to be controlled.
- 7. Surge current waveform per Figure 4 and derate per Figure 2 of the General Data 1500 W at the beginning of this group



Dimensions

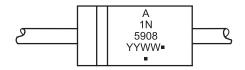


Ć.	Incl	nes	Millimeters		
Dim	Min	Max	Min	Max	
А	0.335	0.374	8.50	9.50	
В	0.189	0.209	4.80	5.30	
D	0.038	0.042	0.96	1.06	
K	1.000		25.40	_	
Р		0.050		1.27	

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.
- 3. LEAD FINISH AND DIAMETER UNCONTROLLED IN DIMENSION P.
- 4. 041A-01 THRU 041A-03 OBSOLETE, NEW STANDARD 041A-04.

Part Marking System



A = Assembly Location 1N5908 = JEDEC Device Number

YY = Year WW = Work Week ■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
1N5908G	Axial Lead (Pb-Free)	500 Units/Box
1N5908RL4G	Axial Lead (Pb-Free)	1500/Tape & Reel

Flow/Wave Soldering (Solder Dipping)

Peak Temperature :	260°C
Dipping Time :	1/16" from the case for 10 seconds

Physical Specifications

Case	Void-free, transfer-molded, thermosetting plastic
Leads	Modified L-Bend providing more contact area to bond pads
Finish	All external surfaces are corrosion resistant and leads are readily solderable
Mounting Position	Any

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ESD119B1W01005E6327XTSA1 ESD5V0J4-TP ESD5V0L1B02VH6327XTSA1 ESD7451N2T5G 19180-510 CPDT-5V0USP-HF
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